

2.5 Gbps 850 nm VCSEL Data Sheet

Part Number: VG2A-7000

Applications: 2.125 / 2.5 / 3.125 Gbps

Absolute Maximum Ratings (T = 25°C):

Parameter	Symbol	Unit	Min.		Max.		Note
Forward Current	$I_{\max}$	mA			15		
Reverse Voltage	V_r	V			5		
Operating Temperature	T_{op}	°C	0		85		
Storage Temperature	T_{stg}	°C	- 40		100		
Maximum Die Exposure	$T_{\max}$	°C			260	For 10 seconds	

Electro-optical Characteristics (T = 25°C, unless noted otherwise):

Parameter	Symbol	Unit	Min.	Typ.	Max.	Test Condition	Note
Threshold Current	I_{th}	mA		3	5		
Ith Temperature Variation	ΔI_{th}	mA	-1.5		1.5	25°C to 95°C	
Forward Voltage	V_f	V		2.0	2.2	@ 10 mA	
Differential Resistance	R_s	Ω		35	50	@ 10 mA	
Reverse Voltage	V_r	V	5			@ -10 μ A	
Slope Efficiency	η	mW/mA	0.3	0.4	0.6	@ 10 mA	
Optical Power	P_o	mW	1.5	3		@ 10 mA	
Slope Efficiency temp-coeff.	$\Delta\eta/\Delta T$	%/°C	-0.6			25-90°C @ 10 mA	
Peak Wavelength	λ	nm	830	845	860	@ 2 mW	
Beam Divergence	θ	deg			30	Full width, $1/e^2$	
Rise Time	τ_r	ps		90		20-80%	
Fall Time	τ_f	ps		100		20-80%	

Chip configuration:

1. Top contact: Anode; Bottom contact: Cathode.
2. Dimension: 225 μ m (Wide) x 425 μ m (Long) x 165 μ m (Thick)

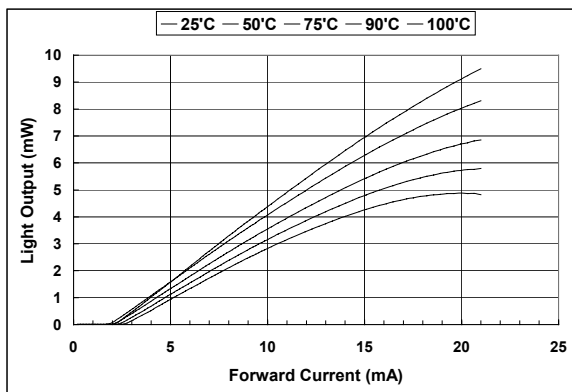
* Specifications are subject to change without notice.
* Screening per customer-specified reject limits is available.

November, 2001

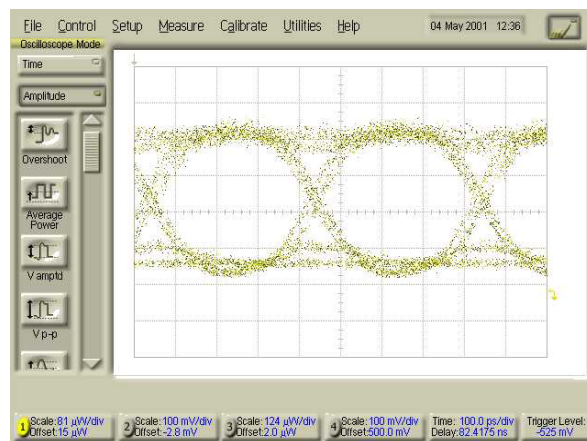


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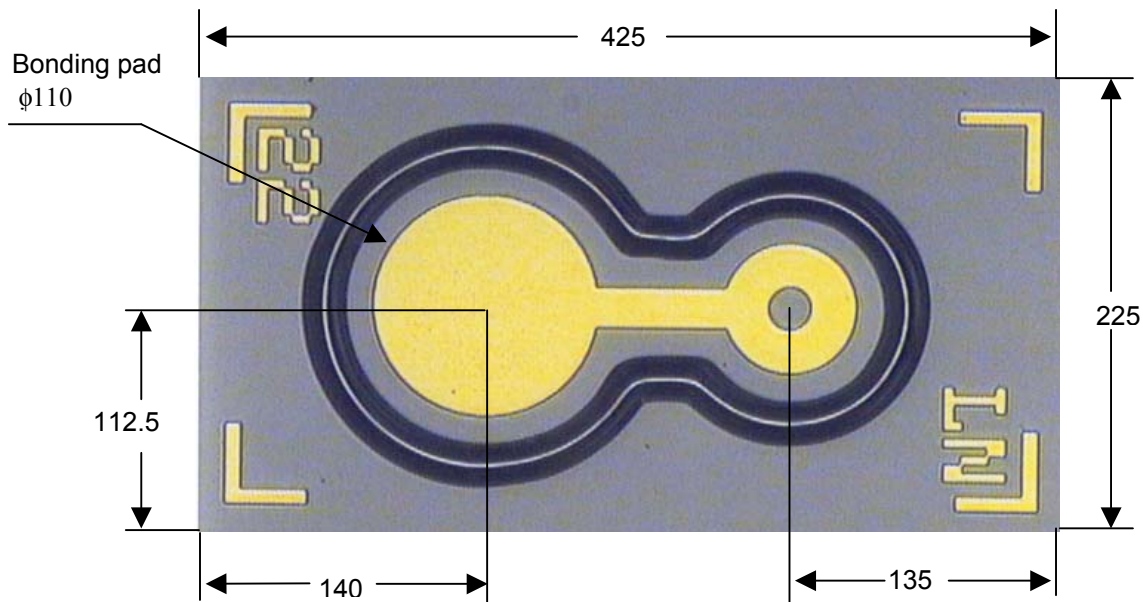
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Light Output vs. Temperature (25 – 100°C)



Eye Diagram at 2.5 Gbps



Unit: μm

Chip Thickness: 165 +/-10

VCSEL Chip Top View

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